

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	30	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient (Note 1a)	78	C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Package Reel Size		Quantity	
.886	FDC8886	SSOT-6	7 "	8 mm	3000 units	

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	cteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	30			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		18		mV/°0	
IDSS	Zero Gate Voltage Drain Current	$V_{DS} = 24 V, V_{GS} = 0 V$			1	μA	
I _{GSS}	Gate to Source Leakage Current, Forward	$V_{GS} = 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			100	nA	
On Chara	cteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250 μA	1.2	1.9	3.0	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_{J}}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		-6		mV/°	
5		V _{GS} = 10 V, I _D = 6.5 A		19	23		
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 6.0 \text{ A}$		30	36	mΩ	
20(01)		V _{GS} = 10 V, I _D = 6.5 A, T _J = 125 °C		25	30	-	
9 _{FS}	Forward Transconductance	V _{DD} = 5 V, I _D = 6.5 A		24		S	
Dynamic C _{iss} C _{oss}	Characteristics Input Capacitance Output Capacitance	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz		348 135	465 180	pF pF	
C _{rss}	Reverse Transfer Capacitance			16	25	pF	
R _g	Gate Resistance			1.2		Ω	
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time			5	10	ns	
t _r	Rise Time	V_{DD} = 15 V, I _D = 6.5 A, V _{GS} = 10 V, R _{GEN} = 6 Ω		1	10	ns	
t _{d(off)}	Turn-Off Delay Time			11	19	ns	
t _f	Fall Time			1	10	ns	
0	Total Gate Charge	V _{GS} = 0 V to 10 V		5.3	7.4	nC	
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 \text{ V to } 4.5 \text{ V}$ $V_{DD} = 15 \text{ V}$		2.5	3.5	nC	
Q _{gs}	Total Gate Charge	$I_{\rm D} = 6.5 \rm{A}$		1.0		nC	
Q _{gd}	Gate to Drain "Miller" Charge			0.8		nC	
-	urce Diode Characteristics						
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 6.5 A$ (Note 2)		0.86	1.2	V	
t _{rr}	Reverse Recovery Time			14	22	ns	
Q _{rr}	Reverse Recovery Charge	I _F = 6.5 A, di/dt = 100 A/μs		3	10	nC	
NOTES:	, ,	1				1	



2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0 %.

a. 78 °C/W when mounted on a 1 in² pad of 2 oz copper

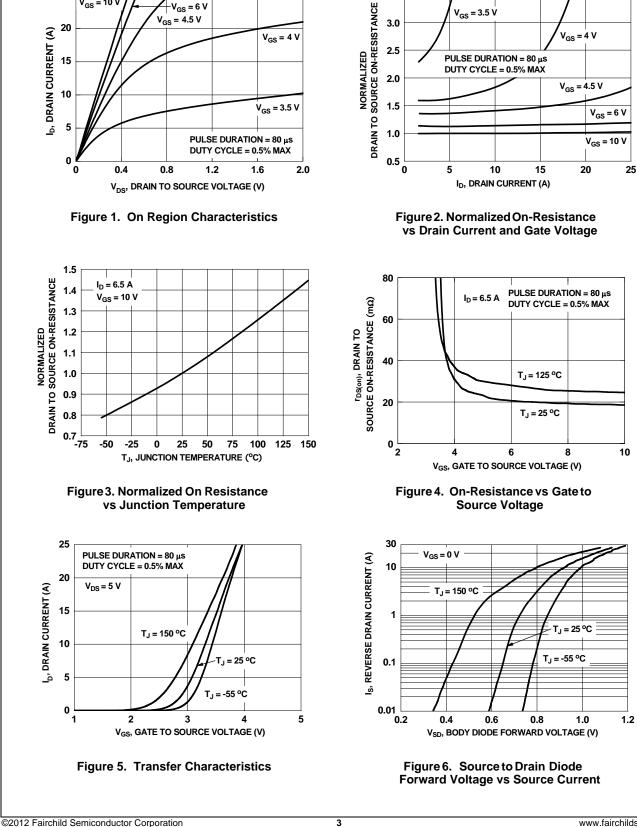
3. As an N-ch device, the negative Vgs rating is for low duty cycle pulse occurrence only. No continuous rating is implied.



b.175 °C/W when mounted on a minimum pad of 2 oz copper

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2



3.5

Typical Characteristics T_J = 25 °C unless otherwise noted

25

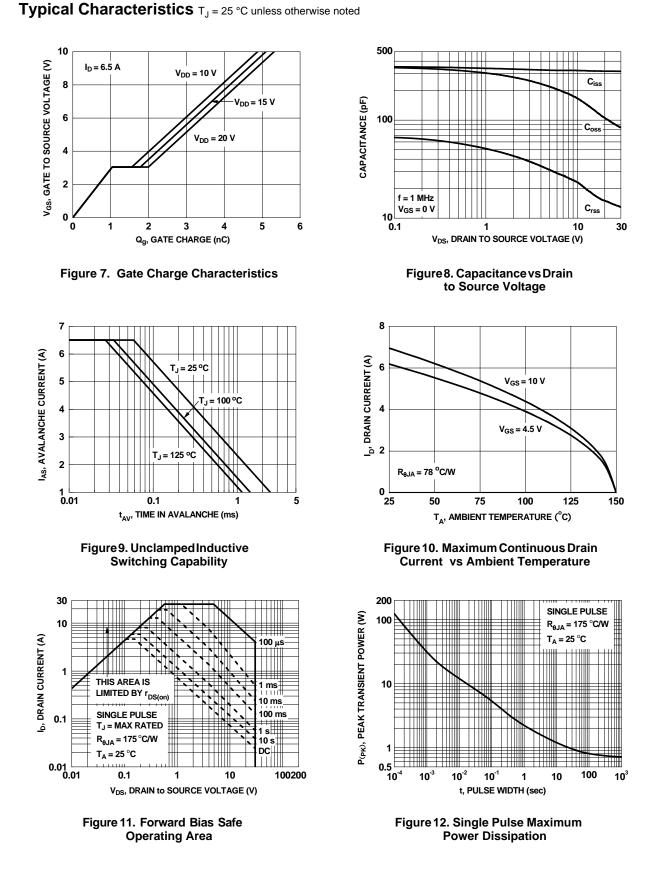
V_{GS} = 10 V

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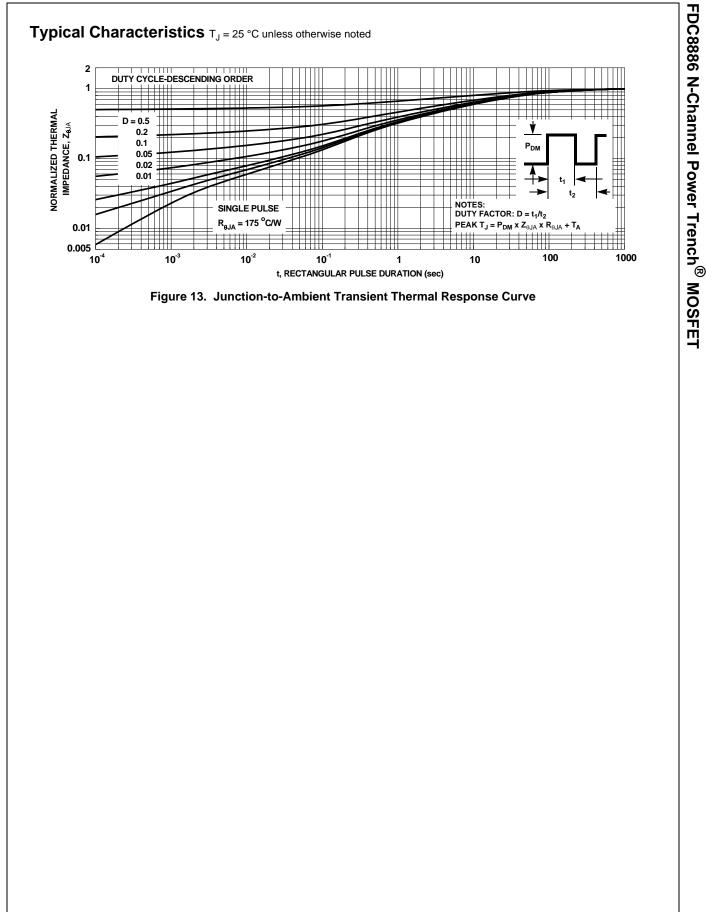
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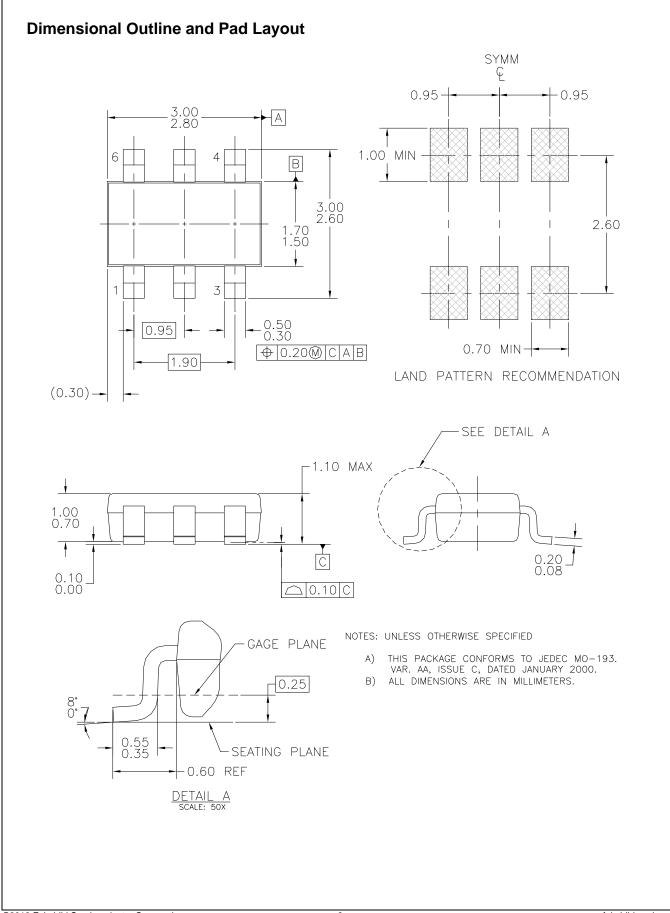




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FDC8886 N-Channel Power Trench[®] MOSFET



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